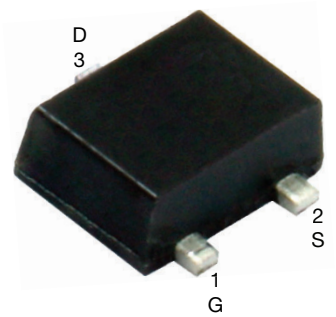
N-Channel 20 V (D-S) MOSFET

SC-89 (3 leads)



Top View

Marking code: J

FEATURES

- TrenchFET® power MOSFET
- Gate-source ESD protected: 1000 V
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

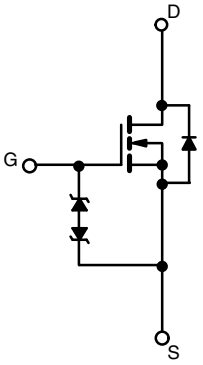
Pb-free

RoHS COMPLIANT

HALOGEN FREE

APPLICATIONS

- Load / power switching for portable devices
- Drivers: relays, solenoids, lamps, hammers, displays, memories
- Battery operated systems
- Power supply converter circuits



N-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	20
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.420
$R_{DS(on)}$ max. (Ω) at V_{GS} = 2.5 V	0.492
$R_{DS(on)}$ max. (Ω) at V_{GS} = 1.8 V	0.597
$R_{DS(on)}$ max. (Ω) at V_{GS} = 1.5 V	0.762
Q_g typ. (nC)	1
I_D (A)	0.53
Configuration	Single

ORDERING INFORMATION	
Package	SC-89
Lead (Pb)-free and halogen-free	Si1062X-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	20	V
Gate-source voltage		V_{GS}	± 8	
Continuous drain current (T_J = 150 °C) [a]	T_A = 25 °C	I_D	0.53 [a, b]	A
	T_A = 70 °C		0.43 [a, b]	
Pulsed drain current (t = 300 µs)		I_{DM}	2	
Continuous source-drain diode current	T_A = 25 °C	I_S	0.18 [a, b]	
Maximum power dissipation [a]	T_A = 25 °C	P_D	0.22 [a, b]	W
	T_A = 70 °C		0.14 [a, b]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYP.	MAX.	UNIT
Maximum junction-to-ambient [b]	t ≤ 5 s	R_{thJA}	440	530	°C/W
	Steady state		540	650	

Notes

a. Surface mounted on 1" x 1" FR4 board

b. t = 5 s

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	20	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA	-	11	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	-1.8	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	0.4	-	1	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 8 V	-	-	± 30	µA
		V_{DS} = 0 V, V_{GS} = ± 4.5 V	-	-	± 1	
Zero gate voltage drain current	I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V	-	-	1	
		V_{DS} = 20 V, V_{GS} = 0 V, T_J = 85 °C	-	-	10	
On-state drain current [a]	$I_{D(on)}$	V_{DS} = ≥ 5 V, V_{GS} = 4.5 V	2	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 4.5 V, I_D = 0.5 A	-	0.350	0.420	Ω
		V_{GS} = 2.5 V, I_D = 0.2 A	-	0.410	0.492	
		V_{GS} = 1.8 V, I_D = 0.2 A	-	0.459	0.597	
		V_{GS} = 1.5 V, I_D = 0.05 A	-	0.510	0.762	
Forward transconductance	g_{fs}	V_{DS} = 10 V, I_D = 0.5 A	-	7.5	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	-	43	-	pF
Output capacitance	C_{oss}		-	14	-	
Reverse transfer capacitance	C_{rss}		-	8	-	
Total gate charge	Q_g	V_{DS} = 10 V, V_{GS} = 8 V, I_D = 0.5 A	-	1.8	2.7	nC
		V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 0.5 A	-	1	2	
Gate-source charge	Q_{gs}		-	0.16	-	
Gate-drain charge	Q_{gd}		-	0.13	-	
Gate resistance	R_g	f = 1 MHz	-	12.2	-	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 10 V, R_L = 20 Ω, I_D ≅ 0.4 A, V_{GEN} = 4.5 V, R_g = 1 Ω	-	2	4	ns
Rise time	t_r		-	14	24	
Turn-off delay time	$t_{d(off)}$		-	16	30	
Fall time	t_f		-	11	20	
Drain-Source Body Diode Characteristics						
Pulse diode forward current [a]	I_{SM}		-	-	2	A
Body diode voltage	V_{SD}	I_S = 0.4 A	-	0.8	1.2	V
Body diode reverse recovery time	t_{rr}	I_F = 0.4 A, di/dt = 100 A/µs	-	10	15	ns
Body diode reverse recovery charge	Q_{rr}		-	2	4	nC
Reverse recovery fall time	t_a		-	5	-	ns
Reverse recovery rise time	t_b		-	5	-	

Notes

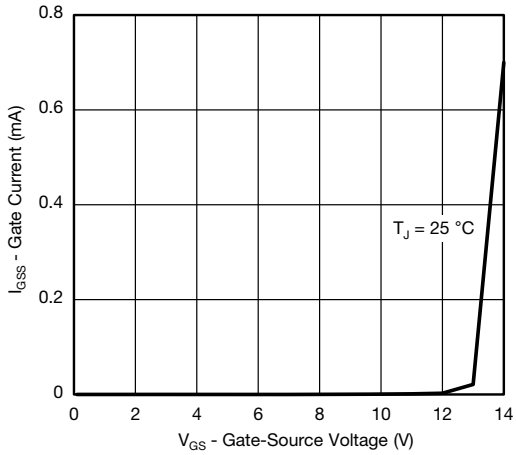
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. Guaranteed by design, not subject to production testing

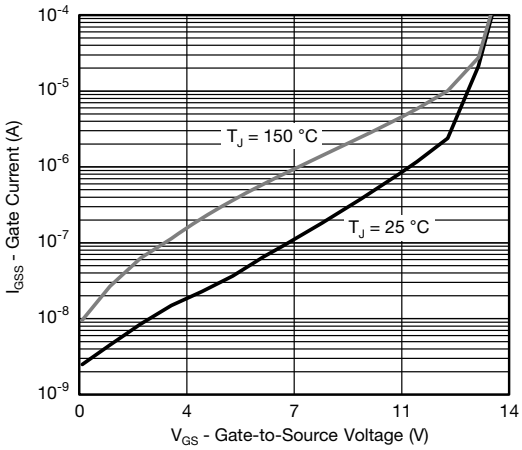
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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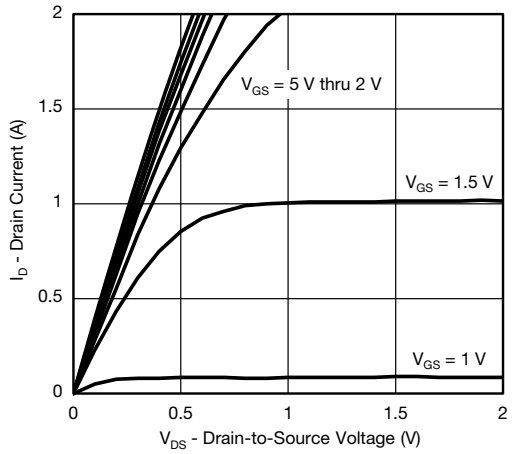
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



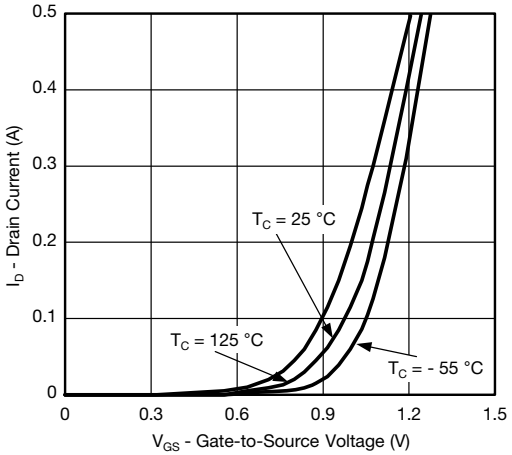
Gate Current vs. Gate-Source Voltage



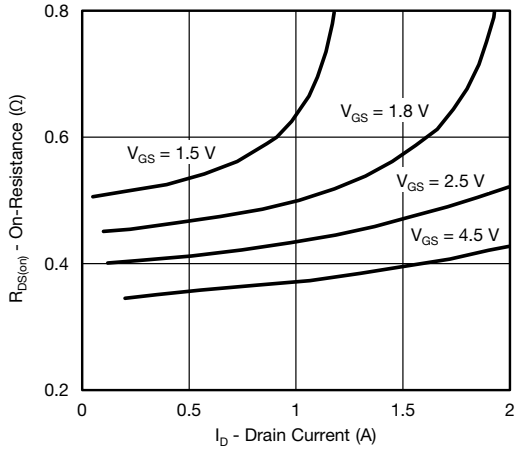
Gate Current vs. Gate-Source Voltage



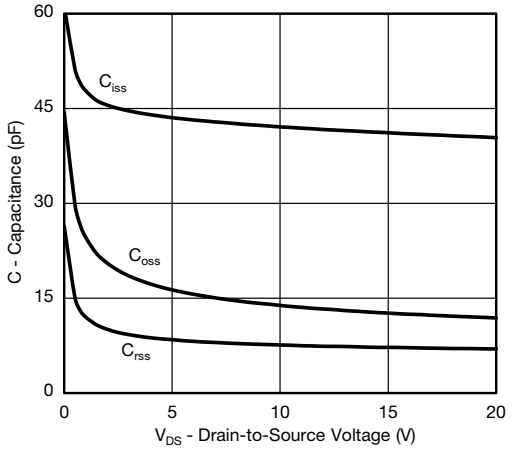
Output Characteristics



Transfer Characteristics



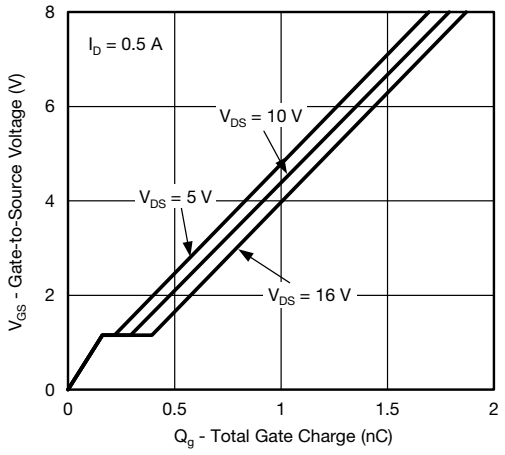
On-Resistance vs. Drain Current



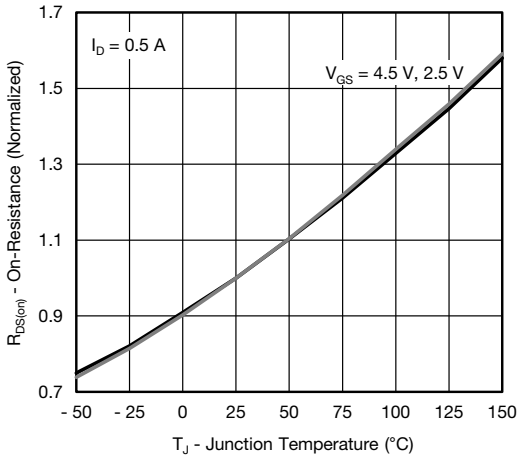
Capacitance

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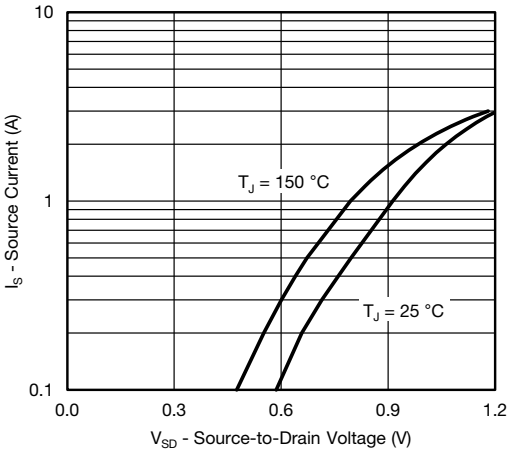
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



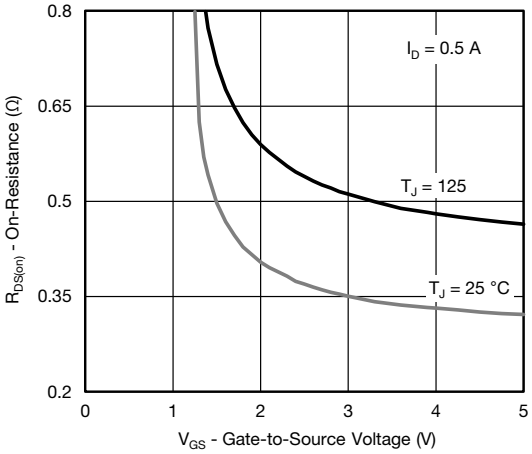
Gate Charge



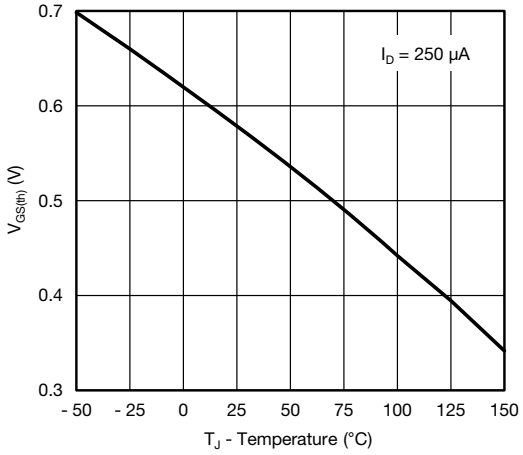
On-Resistance vs. Junction Temperature



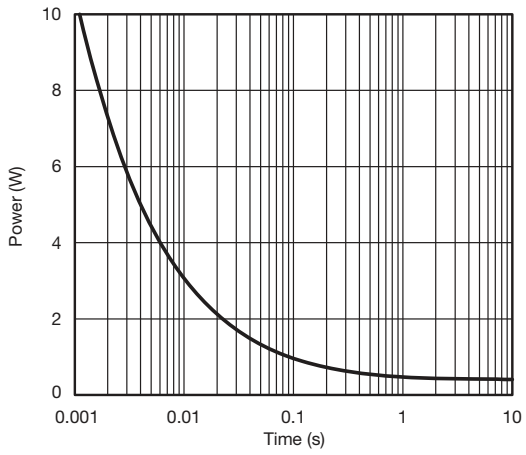
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



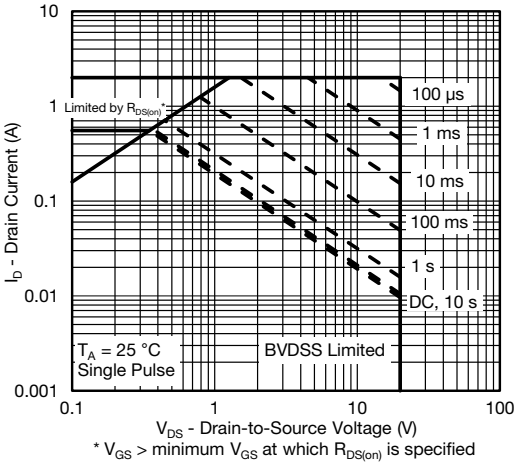
Threshold Voltage



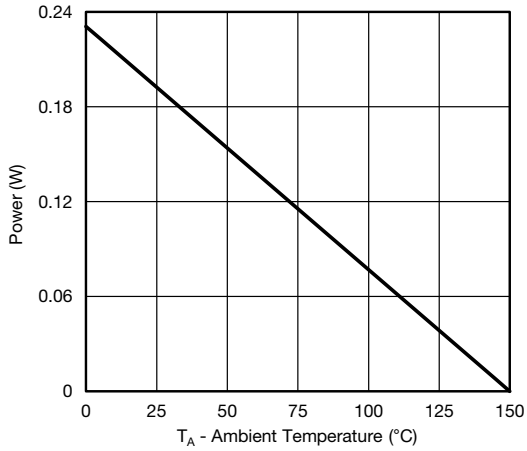
Single Pulse Power, Junction-to-Ambient

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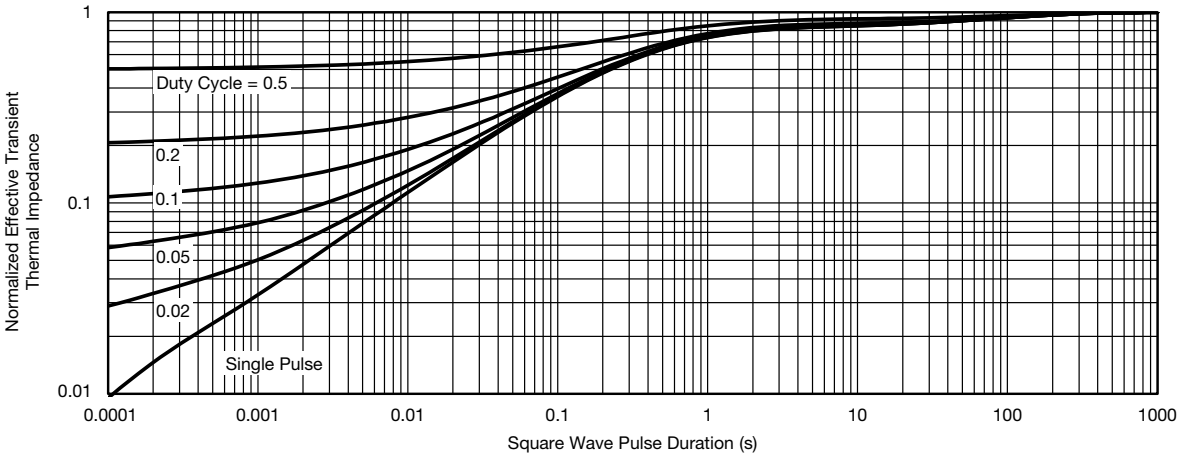
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Safe Operating Area, Junction-to-Ambient



Power Derating, Junction-to-Ambient

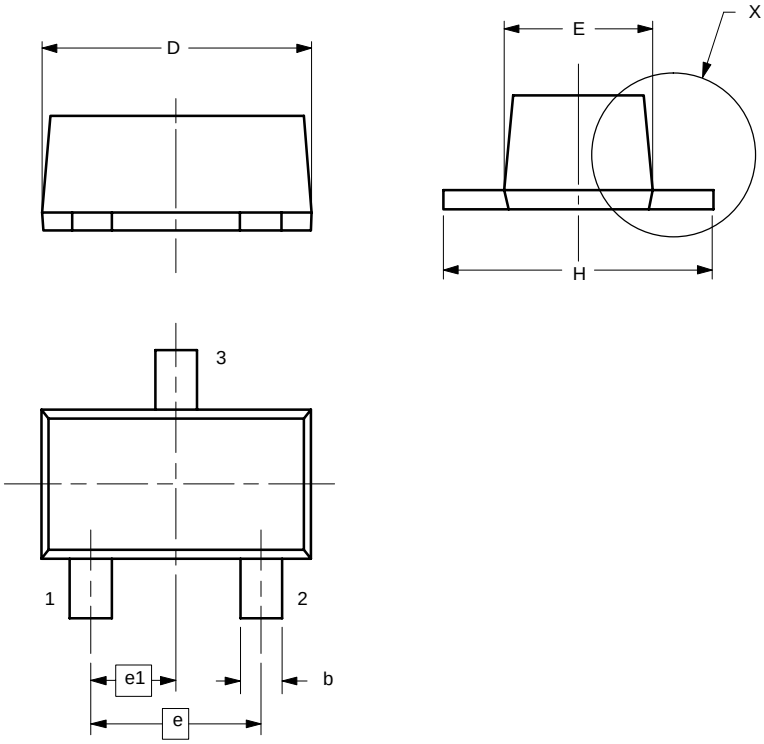


Normalized Thermal Transient Impedance, Junction-to-Ambient

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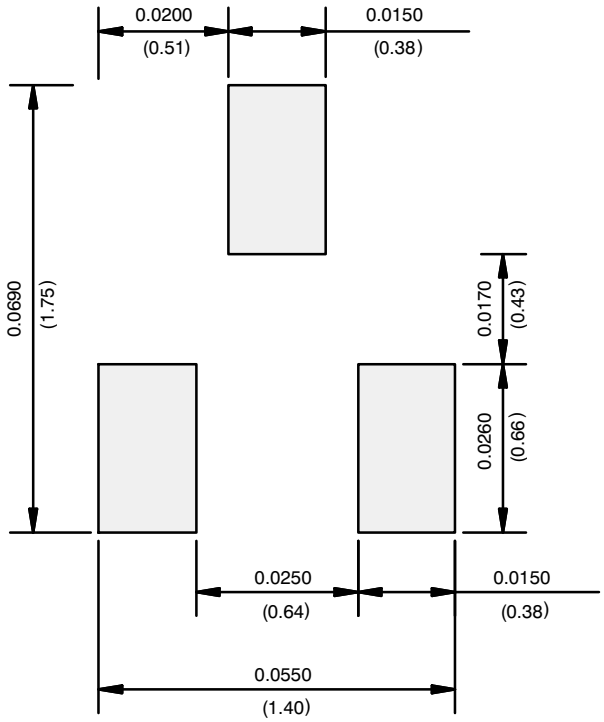
SC89-3



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.60	0.80	0.024	0.031
b	0.23	0.33	0.009	0.013
C	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.75	0.95	0.030	0.037
e	1.00 BSC		0.040 BSC	
e_1	0.50 BSC		0.020 BSC	
H	1.50	1.70	0.059	0.067
L	0.30	0.50	0.012	0.020

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5869

RECOMMENDED MINIMUM PADS FOR SC-89: 3-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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